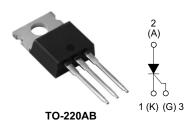


Vishay High Power Products

Phase Control SCR, 10 A



PRODUCT SUMMARY				
V _T at 10 A	< 1.4 V			
I _{TSM}	200 A			
V_{RRM}	800/1200 V			

DESCRIPTION/FEATURES

The 16TTS.. High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS	SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS				
Capacitive input filter T_A = 55 °C, T_J = 125 °C, common heatsink of 1 °C/W	13.5	17	А		

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I _{T(AV)}	Sinusoidal waveform	10	Λ		
I _{RMS}		16	Α		
V _{DRM} /V _{RRM}	Range (1)	800/1200	V		
I _{TSM}		200	Α		
V _T	10 A, T _J = 25 °C	1.4	V		
dV/dt		500	V/µs		
dI/dt		150	A/μs		
T _J	Range	- 40 to 125	°C		

Note

⁽¹⁾ For higher voltage up to 1600 V contact factory

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
16TTS08	800	10			
16TTS12	1200	1200	10		

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST SOMBITIONS		VALUES		UNITS
PARAMETER	STINIBUL		TEST CONDITIONS		MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 98 °C, 1	= 98 °C, 180° conduction, half sine wave 10		0	
Maximum RMS on-state current	I _{RMS}			1	6	A
Maximum peak, one-cycle,		10 ms sine p	ulse, rated V _{RRM} applied	17	70	_ ^
non-repetitive surge current	I _{TSM}	10 ms sine p	ulse, no voltage reapplied	20	00	
Maximum 12+ for fusing	l ² t	10 ms sine p	ulse, rated V _{RRM} applied	144		- A ² s
Maximum I ² t for fusing	1-1	10 ms sine p	ms sine pulse, no voltage reapplied		00	
Maximum I $^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 to 10 r	ms, no voltage reapplied	20	00	A²√s
Maximum on-state voltage drop	V_{TM}	10 A, T _J = 25 °C		1	.4	V
On-state slope resistance	r _t	T 405.00		24	1.0	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C		1	.1	V
Maximum various and divest leakage accurant	1 /1	T _J = 25 °C	V Dated V A/	0.5		
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C	$V_R = Rated V_{RRM}/V_{DRM}$	10		
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A 16TTS08, 16TTS12		-	100	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load		20	00	
Maximum rate of rise of off-state voltage	dV/dt			50	00	V/µs
Maximum rate of rise of turned-on current	dl/dt			15	50	A/μs

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P_{GM}		8.0	W	
Maximum average gate power	$P_{G(AV)}$		2.0	VV	
Maximum peak positive gate current	+ I _{GM}		1.5	Α	
Maximum peak negative gate voltage	- V _{GM}		10	V	
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	90	mA	
		Anode supply = 6 V, resistive load, T _J = 25 °C	60		
		Anode supply = 6 V, resistive load, T _J = 125 °C	35		
		Anode supply = 6 V, resistive load, T _J = - 65 °C	3.0		
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	v	
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	V	
Maximum DC gate voltage not to trigger	V_{GD}	$T_J = 125 ^{\circ}\text{C}, V_{\text{DRM}} = \text{Rated value}$ 0.2 2.0			
Maximum DC gate current not to trigger	I _{GD}			mA	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs
Typical turn-off time	t _q	1J=125 C	110	



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T_J , T_{Stg}		- 40 to 125	°C	
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.3		
Maximum thermal resistance, junction to ambient		R_{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque ———	minimum			6 (5)	kgf ⋅ cm	
	maximum			12 (10)	(lbf · in)	
Marking device			Coop at the TO COO A D	16TTS08		
			Case style TO-220AB		16TTS12	

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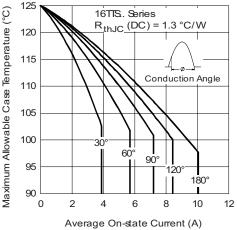


Fig. 1 - Current Rating Characteristics

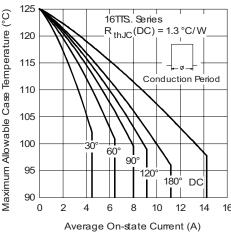


Fig. 2 - Current Rating Characteristics

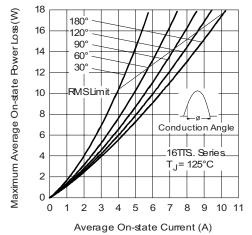


Fig. 3 - On-State Power Loss Characteristics

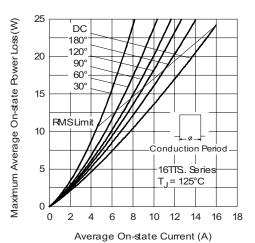


Fig. 4 - On-State Power Loss Characteristics

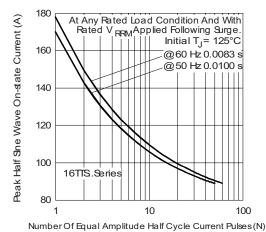


Fig. 5 - Maximum Non-Repetitive Surge Current

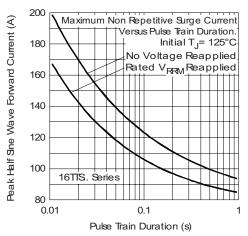


Fig. 6 - Maximum Non-Repetitive Surge Current



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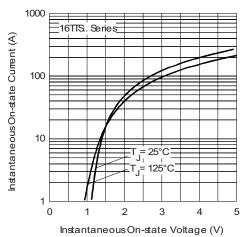


Fig. 7 - On-State Voltage Drop Characteristics

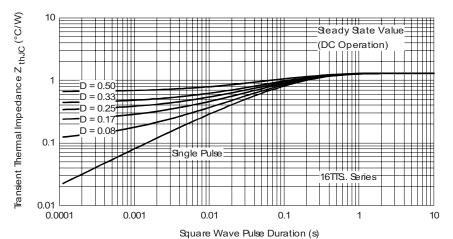


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

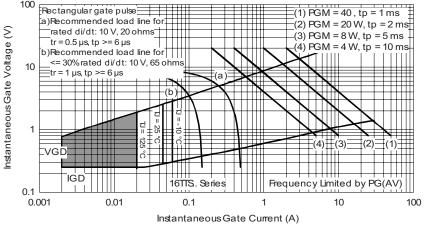


Fig. 9 - Gate Characteristics

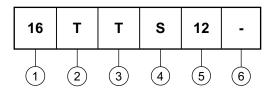
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ORDERING INFORMATION TABLE

Device code



1 - Current rating

2 - Circuit configuration:

T = Single thyristor

3 - Package:

T = TO-220AB

4 - Type of silicon:

S = Converter grade

5 - Voltage code x 100 = V_{RRM} —

08 = 800 V 12 = 1200 V

6 - • None = Standard production

• PbF = Lead (Pb)-free

Note: For higher voltage up to 1600 V contact factory

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95222					
Part marking information	http://www.vishay.com/doc?95225				



Vishay

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